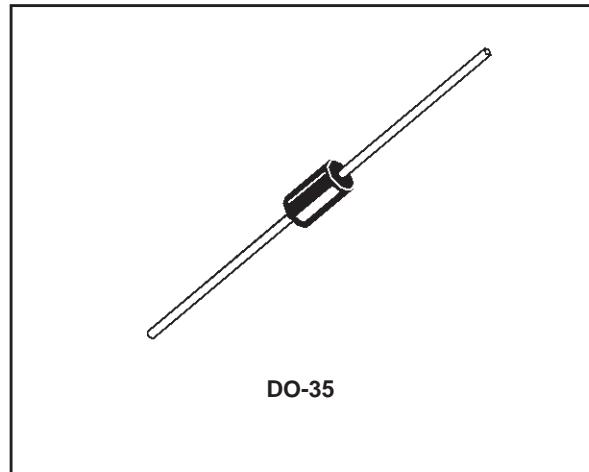


## SMALL SIGNAL SCHOTTKY DIODE

### DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching. These devices have integrated protection against excessive voltage such as electrostatic discharges.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		BAT47	BAT48	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		20	40	V
$I_F$	Forward Continuous Current*		350		mA
$I_{FRM}$	Repetitive Peak Forward Current*		1		A
$I_{FSM}$	Surge non Repetitive Forward Current*		7.5		A
	$t_p = 10\text{ms}$	1.5			
$P_{tot}$	Power Dissipation*	$T_a = 25^\circ\text{C}$	330		mW
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 65 to + 150 - 65 to + 125		$^\circ\text{C}$ $^\circ\text{C}$
$T_L$	Maximum Temperature for Soldering during 10s at 4mm from Case		230		$^\circ\text{C}$

### THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th(j-l)}$	Junction-ambient*	300	$^\circ\text{C/W}$

\* On infinite heatsink with 4mm lead length

## BAT47 / BAT48

---

### ELECTRICAL CHARACTERISTICS

#### STATIC CHARACTERISTICS

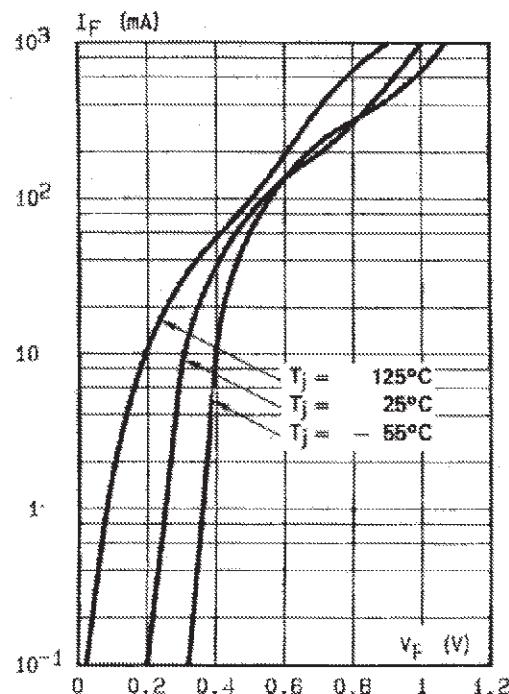
Symbol	Test Conditions		Min.	Typ.	Max.	Unit	
$V_{(BR)}$	$I_R = 10\mu A$		BAT47	20		V	
	$I_R = 25\mu A$		BAT48	40			
$V_F^*$	$T_j = 25^\circ C$	$I_F = 0.1mA$	All Types		0.25	V	
	$T_j = 25^\circ C$	$I_F = 1mA$			0.3		
	$T_j = 25^\circ C$	$I_F = 10mA$			0.4		
	$T_j = 25^\circ C$	$I_F = 30mA$	BAT47		0.5		
	$T_j = 25^\circ C$	$I_F = 150mA$			0.8		
	$T_j = 25^\circ C$	$I_F = 300mA$			1		
	$T_j = 25^\circ C$	$I_F = 50mA$	BAT48		0.5		
	$T_j = 25^\circ C$	$I_F = 200mA$			0.75		
	$T_j = 25^\circ C$	$I_F = 500mA$			0.9		
$I_R^*$	$T_j = 25^\circ C$	$V_R = 1.5V$	All Types		1	$\mu A$	
	$T_j = 60^\circ C$				10		
	$T_j = 25^\circ C$	$V_R = 10V$	BAT47		4		
	$T_j = 60^\circ C$				20		
	$T_j = 25^\circ C$	$V_R = 20V$			10		
	$T_j = 60^\circ C$				30		
	$T_j = 25^\circ C$	$V_R = 10V$	BAT48		2		
	$T_j = 60^\circ C$				15		
	$T_j = 25^\circ C$	$V_R = 20V$			5		
	$T_j = 60^\circ C$				25		
	$T_j = 25^\circ C$	$V_R = 40V$			25		
	$T_j = 60^\circ C$				50		

#### DYNAMIC CHARACTERISTICS

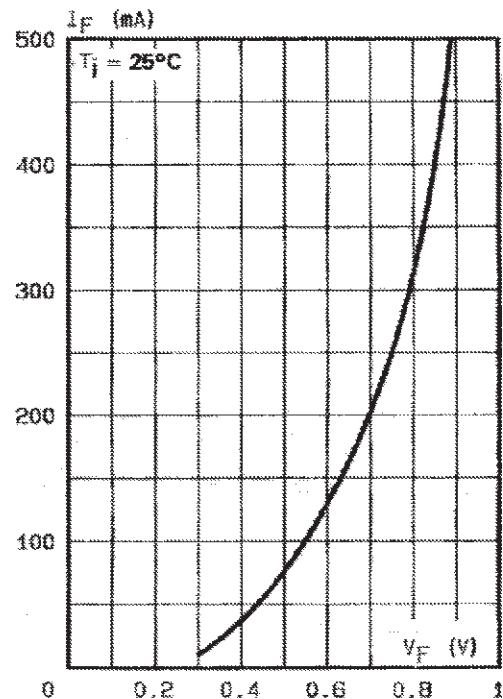
Symbol	Test Conditions		Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ C$	$V_R = 0V$	$f = 1MHz$		20	pF
	$T_j = 25^\circ C$	$V_R = 1V$			12	

\* Pulse test:  $t_p \leq 300\mu s$   $\delta < 2\%$ .

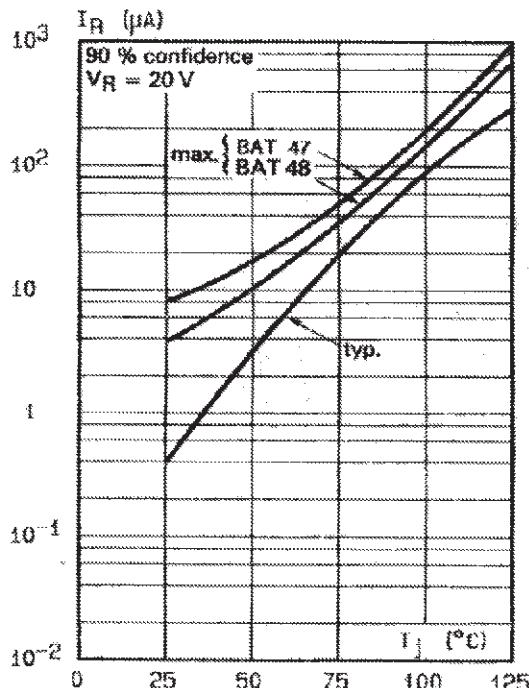
**Fig. 1:** Forward current versus forward voltage at different temperatures (typical values).



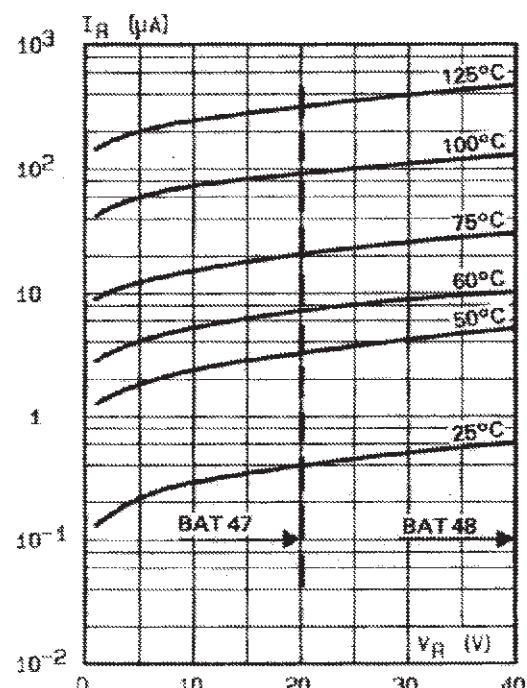
**Fig. 2:** Forward current versus forward voltage (typical values).



**Fig. 3:** Reverse current versus junction temperature.



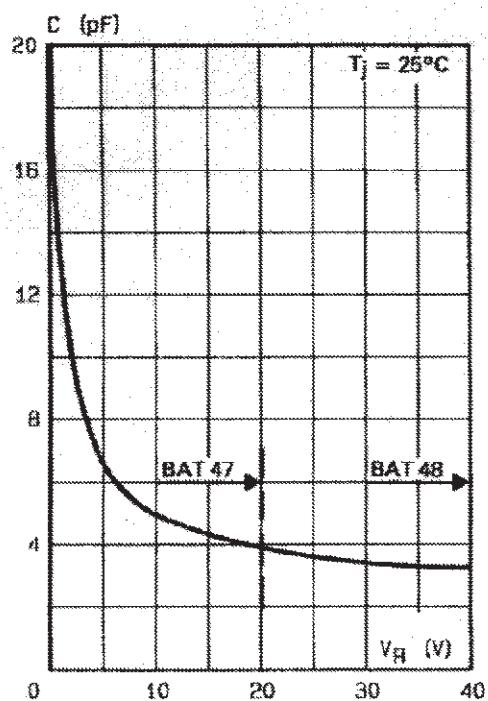
**Fig. 4:** Reverse current versus continuous reverse voltage (typical values).



## BAT47 / BAT48

---

**Fig. 5:** Capacitance C versus reverse applied voltage  $V_R$  (typical values).



**PACKAGE MECHANICAL DATA**  
DO-35

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	3.05	4.50	0.120	0.177
B	1.53	2.00	0.060	0.079
C	28.00		1.102	
D	0.458	0.558	0.018	0.022

Cooling method: by convection and conduction.

Marking: clear, ring at cathode end.

Weight: 0.015g

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.

STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All rights reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia  
Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

<http://www.st.com>